

# Dual EIA-423/EIA-232D Line Driver

The MC3488A dual is single–ended line driver has been designed to satisfy the requirements of EIA standards EIA–423 and EIA–232D, as well as CCITT X.26, X.28 and Federal Standard FIDS1030. It is suitable for use where signal wave shaping is desired and the output load resistance is greater than 450 ohms. Output slew rates are adjustable from 1.0  $\mu s$  to 100  $\mu s$  by a single external resistor. Output level and slew rate are insensitive to power supply variations. Input undershoot diodes limit transients below ground and output current limiting is provided in both output states.

The MC3488A has a standard 1.5 V input logic threshold for TTL or NMOS compatibility.

- PNP Buffered Inputs to Minimize Input Loading
- Short Circuit Protection
- Adjustable Slew Rate Limiting
- MC3488A Equivalent to 9636A
- Output Levels and Slew Rates are Insensitive to Power Supply Voltages
- No External Blocking Diode Required for VFF Supply
- Second Source μA9636A

# MC3488A

# DUAL EIA-423/EIA-232D DRIVER

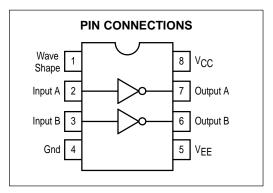
SEMICONDUCTOR
TECHNICAL DATA



P1 SUFFIX PLASTIC PACKAGE CASE 626

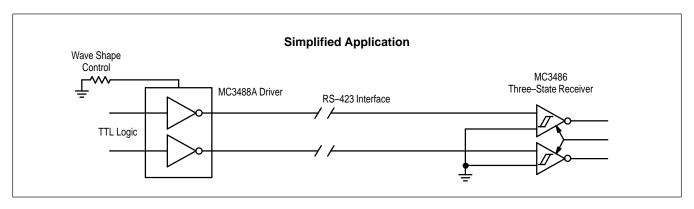
D SUFFIX
PLASTIC PACKAGE
CASE 751
(SO-8)





#### **ORDERING INFORMATION**

Device	Operating Temperature Range	Package
MC3488AP	$T_{\Delta} = 0 \text{ to } +70^{\circ}\text{C}$	Plastic DIP
MC3488AD	1A = 0 t0 +70 C	SO-8



# MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Power Supply Voltages	V <sub>CC</sub>	+ 15 – 15	V
Output Current Source Sink	10 + 10 -	+ 150 - 150	mA
Operating Ambient Temperature	TA	0 to + 70	°C
Junction Temperature Range	TJ	150	°C
Storage Temperature Range	T <sub>stg</sub>	- 65 to + 150	°C

## **RECOMMENDED OPERATING CONDITIONS**

Characteristic	Symbol	Min	Тур	Max	Unit
Power Supply Voltages	V <sub>CC</sub> V <sub>EE</sub>	10.8 - 13.2	12 – 12	13.2 - 10.8	V
Operating Temperature Range	TA	0	25	70	°C
Wave Shaping Resistor	R <sub>WS</sub>	10	-	1000	kΩ

# TARGET ELECTRICAL CHARACTERISTICS (Unless otherwise noted, specifications apply over recommended operating conditions)

Characteristic	Symbol	Min	Тур	Max	Unit
Input Voltage – Low Logic State	VIL	-	_	0.8	V
Input Voltage – High Logic State	ViH	2.0	-	-	V
Input Current – Low Logic State (V <sub>IL</sub> = 0.4 V)	IIL	- 80	-	-	μА
Input Current – High Logic State (V <sub>IH</sub> = 2.4 V) (V <sub>IH</sub> = 5.5 V)	I <sub>IH1</sub>	- -	- -	10 100	μА
Input Clamp Diode Voltage $(I_{IK} = -15 \text{ mA})$	VIK	<b>– 1.5</b>	-	_	V
Output Voltage – Low Logic State $ \begin{array}{ll} (R_L = \infty) & EIA423 \\ (R_L = 3.0 \ k\Omega) & EIA232D \\ (R_L = 450 \ \Omega) & EIA423 \end{array} $	VoL	- 6.0 - 6.0 - 6.0	- - -	- 5.0 - 5.0 - 4.0	V
Output Voltage – High Logic State $ \begin{array}{ll} (R_L = \infty) & EIA423 \\ (R_L = 3.0 \ \mathrm{k}\Omega) & EIA232D \\ (R_L = 450 \ \Omega) & EIA423 \end{array} $	Voн	5.0 5.0 4.0	- - -	6.0 6.0 6.0	V
Output Resistance $(R_L \ge 450 \Omega)$	RO	-	25	50	Ω
Output Short–Circuit Current (Note 2) (Vin = V <sub>Out</sub> = 0 V) (Vin = VIH(Min), V <sub>Out</sub> = 0 V)	IOSH IOSL	– 150 + 15	- -	– 15 + 150	mA
Output Leakage Current (Note 3) $ (V_{CC} = V_{EE} = 0 \text{ V}, -6.0 \text{ V} \leq V_0 \leq 6.0 \text{ V}) $	l <sub>ox</sub>	- 100	-	100	μА
Power Supply Currents $(R_W = 100 \text{ k}\Omega, R_L = \infty, V_{IL} \leqslant V_{in} \leqslant V_{IH})$	ICC IEE	- - 18	- -	+ 18 -	mA

NOTES: 1. Devices should not be operated at these values. The "Electrical Characteristics" provide conditions for actual device operation.
2. One output shorted at a time.
3. No V<sub>EE</sub> diode required.

**TRANSITION TIMES** (Unless otherwise noted,  $C_L$  = 30 pF, f = 1.0 kHz,  $V_{CC}$  = -  $V_{EE}$  = 12.0 V  $\pm$  10%,  $T_A$  = 25°C,  $R_L$  = 450  $\Omega$ . Transition times measured 10% to 90% and 90% to 10%)

Characteristic	Symbol	Min	Тур	Max	Unit
Transition Time, Low–to–High State Output $ \begin{array}{l} (R_W=10~k\Omega) \\ (R_W=100~k\Omega) \\ (R_W=500~k\Omega) \\ (R_W=1000~k\Omega) \end{array} $	<sup>t</sup> TLH	0.8 8.0 40 80	- - - -	1.4 14 70 140	μѕ
Transition Time, High–to–Low State Output $ \begin{array}{l} (R_W=10~k\Omega) \\ (R_W=100~k\Omega) \\ (R_W=500~k\Omega) \\ (R_W=500~k\Omega) \\ (R_W=1000~k\Omega) \end{array} $	<sup>†</sup> THL	0.8 8.0 40 80	- - - -	1.4 14 70 140	μѕ

Figure 1. Test Circuit and Waveforms for Transition Times

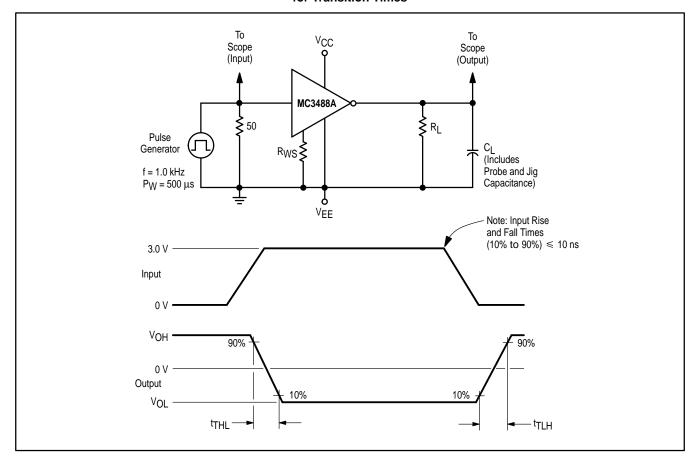


Figure 2. Output Transition Times versus Wave Shape Resistor Value

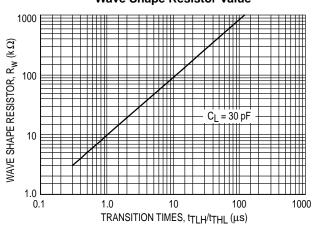


Figure 3. Input/Output Characteristics versus Temperature

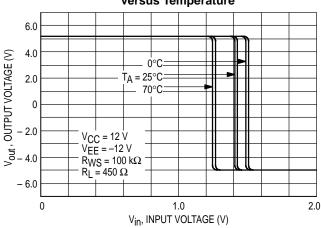
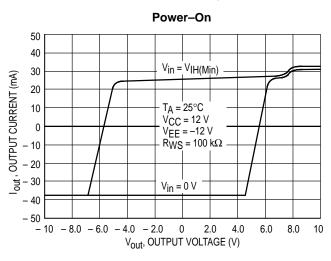


Figure 4. Output Current versus Output Voltage



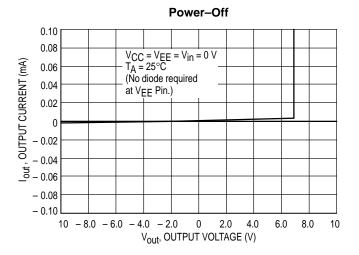


Figure 5. Supply Current versus Temperature

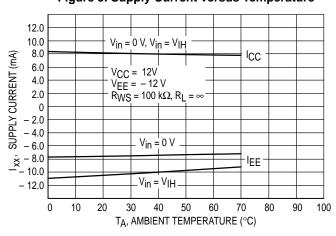
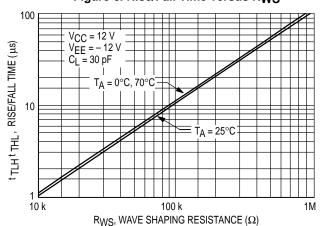
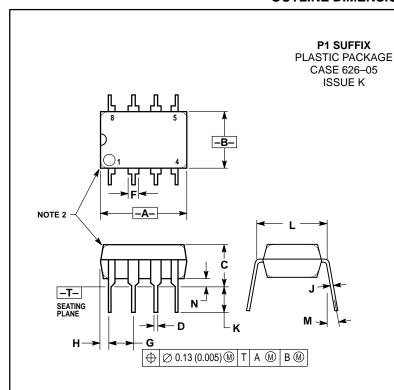


Figure 6. Rise/Fall Time versus Rws



## **OUTLINE DIMENSIONS**



#### NOTES:

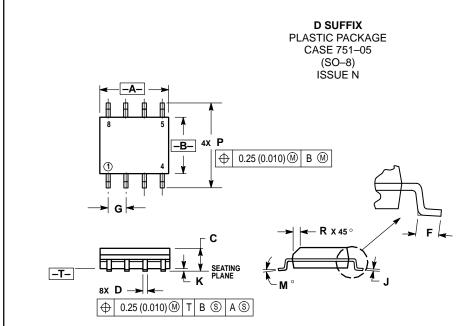
- O LES:

  1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.

  2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).

  3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.40	10.16	0.370	0.400
В	6.10	6.60	0.240	0.260
С	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54	BSC	0.100	BSC
Н	0.76	1.27	0.030	0.050
۲	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62	BSC	0.300	BSC
M	_	10°		10°
N	0.76	1.01	0.030	0.040



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRISION ALLOWARI F DAMBAR PROTRUSION. ALLOWABLE DAMBAR
  PROTRUSION SHALL BE 0.127 (0.005) TOTAL
  IN EXCESS OF THE D DIMENSION AT
  MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.80	5.00	0.189	0.196
В	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050	BSC
J	0.18	0.25	0.007	0.009
K	0.10	0.25	0.004	0.009
М	0 °	7°	0 °	7°
Р	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.010

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